Claims

the corresponding claims in the original Replace application with the following amended claims:

30. A solid state light emitting device, comprising:

at least two active layers;

at least two pairs of oppositely doped layers, each of said active layers sandwiched between one of said pairs of oppositely doped layers, each of said pairs of oppositely doped layers causing its respective one of said active layers to emit light at predetermined wavelength in response electrical bias across said at least two pairs; and

a doped substrate, said active layers and said pairs of oppositely doped layers disposed on said substrate such that said substrate absorbs at least some of said light from at least one of said active layers and re-emits light at a different wavelength.

The light emitting device of claim 30, that emits 31. light which is a combination of light from said active layers and said substrate.

The light emitting device of claim 30, comprising a LED, said active layers emitting one color of light, said substrate doped throughout with more than one impurity such that it absorbs the light from said active layers, and reemit more than one color of light.

The light emitting device of claim 30, comprising electrical circuitry integrated with said device on a common substrate.

Respectfully submitted,

February **20**, 2002

Jage G. Heybl

Actorney for Applicants Registration No. 42,661

KOPPEL JACOBS PATRICK & HEYBL 555 St. Charles Drive, Suite #107 Thousand Oaks, CA 91360 (805)373-0060